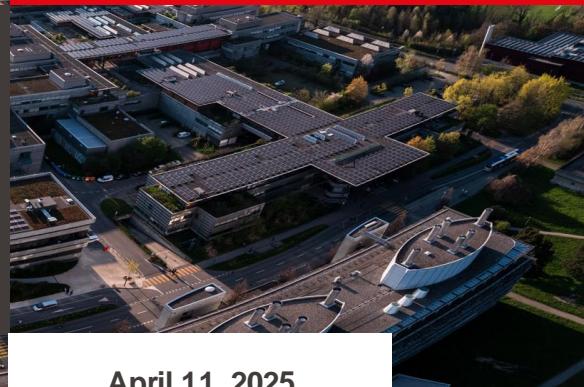




# Advanced simulations of solar cell devices

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# Creating surface from bulk

- Open bulk structure in the VMD (***vmd FAPbI3\_2x2x2.pdb***)
- Visualize periodic box of the system – in TkConsole: ***pbc box***
- Get periodic boundary conditions dimensions: ***pbc get***

```
>Main< (Downloads) 2 % pbc get
{12.814000 12.532000 12.676000 90.000000 90.000000 90.000000}
```

- We plan to create surface in z dimension - need to create thicker layer in the z dimension to have bulk-like properties in the middle of the layer => need to extend box in z dimension: ***pbc set {12.814000 12.532000 50.000}***
- Move the system up along the z axis: ***set sel [atomselect top "all"] \$sel moveby {0.0 0.0 15.0}***
- Save the structure e.g ***FAPbI3\_2x2x2\_surf1.pdb***
- Move the system in along the same axis by the same distance as in bulk: ***\$sel moveby {0.0 0.0 12.676}***
- Save the structure in new file e.g. ***FAPbI3\_2x2x2\_surf2.pdb***
- Exit vmd

# Creating surface from bulk

- Combine two files in the single pdb file (text editor or linux terminal):  
`cat FAPbI3_2x2x2_surf2.pdb FAPbI3_2x2x2_surf1.pdb > FAPbI3_2x2x4_surf.pdb`
- Remove lines with **END** and **CRYST1** in the middle of the merged FAPbI3\_2x2x4\_surf.pdb file (either in vmd or text editor)

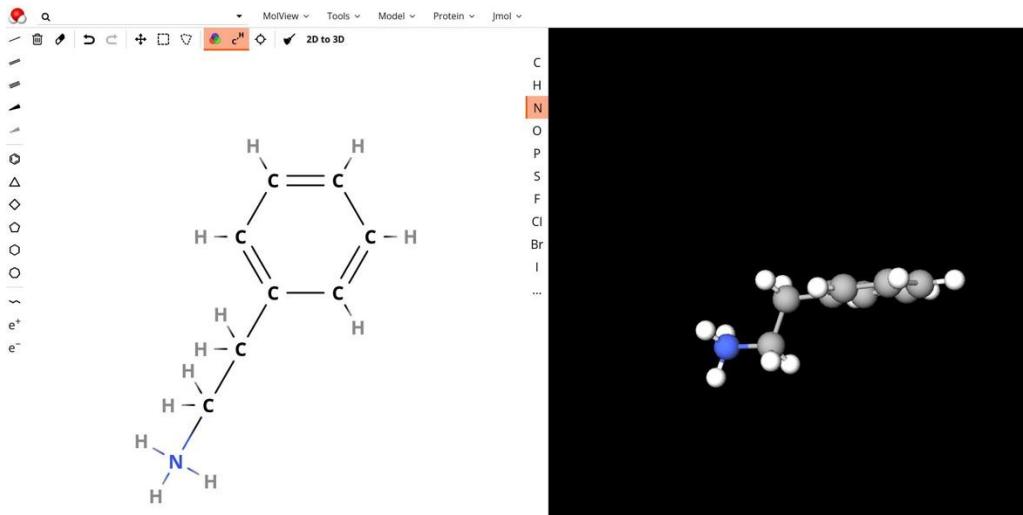
ATOM	94	I	UNL	X	16	9.611	12.434	40.352	0.00	0.00	I
ATOM	95	I	UNL	X	15	6.407	9.167	40.352	0.00	0.00	I
ATOM	96	I	UNL	X	16	6.407	12.029	37.183	0.00	0.00	I
END											
CRYST1	12.814		12.532	50.000	90.00	90.00	90.00	P	1	1	
ATOM	1	C	UNL	X	1	3.204	3.262	18.169	0.00	0.00	C
ATOM	2	N	UNL	X	1	4.368	2.667	18.169	0.00	0.00	N
ATOM	3	N	UNL	X	1	2.039	2.667	18.169	0.00	0.00	N

Lines to be removed

# Surface passivation – building molecule

- Create passivation molecule for example using online molview online tool

<https://molview.org/>



- Convert the .mol file format to pdb

<https://www.cheminfo.org/Chemistry/Ceminformatics/FormatConverter/index.html>

- Remove all the **CONNECT** and **MASTER** lines from the pdb file.

# Surface passivation

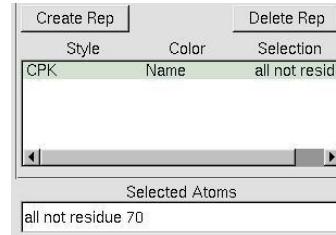
- Open 2D system in vmd and remove single FA molecule from the surface
  - Get the FA index
    - Mouse → Label → Atoms and click on FA to be removed)
    - In the vmd terminal window you should see information about residue

```

Info) molecule id: 0
Info) trajectory frame: 0
Info) name: C
Info) type: C
Info) index: 168
Info) residue: 70 ←
Info) resname: UNL
Info) resid: 13
Info) chain: X
Info) segname:
Info) x: 9.611000
Info) y: 9.528000
Info) z: 18.169001
Info) Added new Atoms label UNL13:C

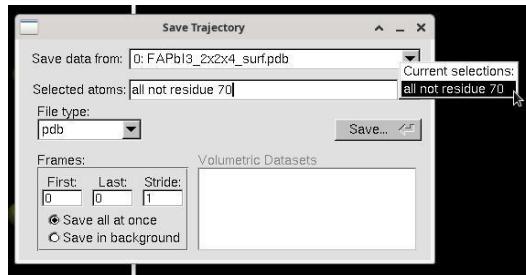
```

Selected residue



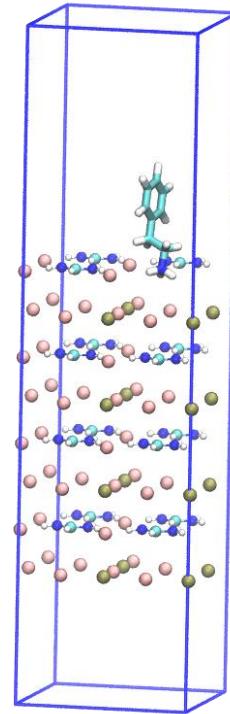
- Create representation with the single FA missing
- Save the structure of the specified representation with new name e.g.

**FAPbI3\_2x2x4\_surf\_prep.pdb**



# Surface passivation

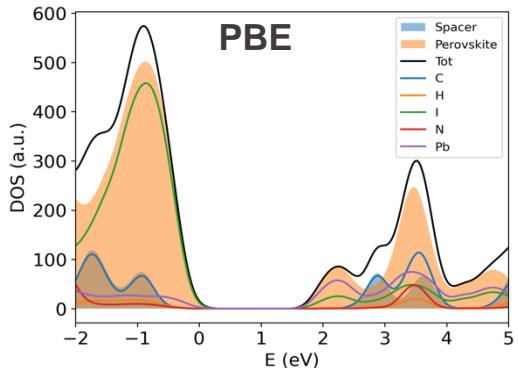
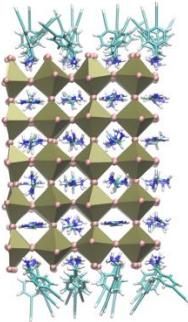
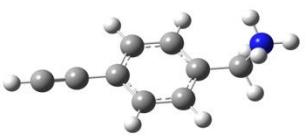
- Open 2D system in vmd and remove single FA molecule from the surface
- Load the passivating molecule (structure.pdb) and reorient to NH3 group replacing missing FA
  - File → Load Molecule load structure.pdb
  - Mouse → Move → Molecule and using mouse orient the passivating molecule in desired way
  - Save coordinates of the shifted molecule (e.g. as structure\_shifted.pdb)
- Close vmd and combine files of the surface without single FA and the passivating molecule: ***cat FAPbI3\_2x2x4\_surf\_prep.pdb structure\_shifted.pdb > FAPbI3\_2x2x4\_passivated.pdb***
- Remove lines with **END** and **CRYST1** in the middle of the merged file
- Check the final structure in vmd



- Requirements for the good passivating layer:
  - Protection from the moisture
    - perovskites are ionic materials → dissolved by water
  - Defect passivation
    - Usually with  $\text{NH}_3^+$  group and  $\text{I}^-$  counter ions – passivation of iodide vacancies
  - Larger binding energy than FA (to replace FA molecules and stabilize the surface)
  - Not to block charge extraction from active layer to ETL/HTL layers
    - Smaller molecules
    - **Electroactive molecules** → enhancing charge transport or selective for holes/electrons

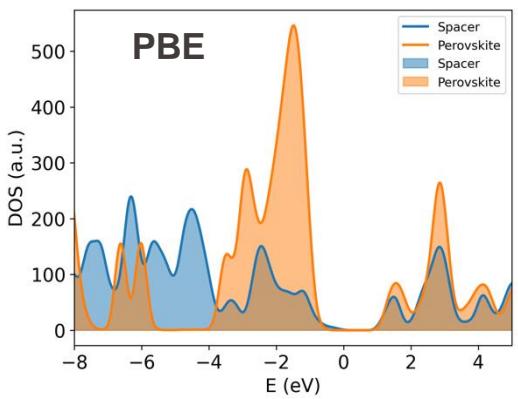
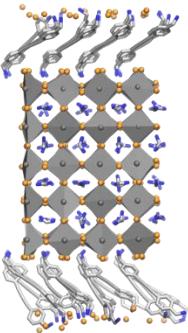
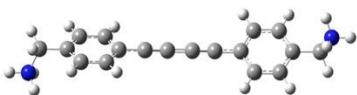
# PDOS of the passivated and multilayer systems

BMAA



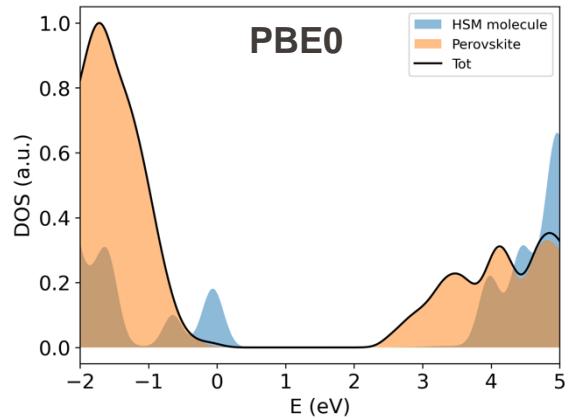
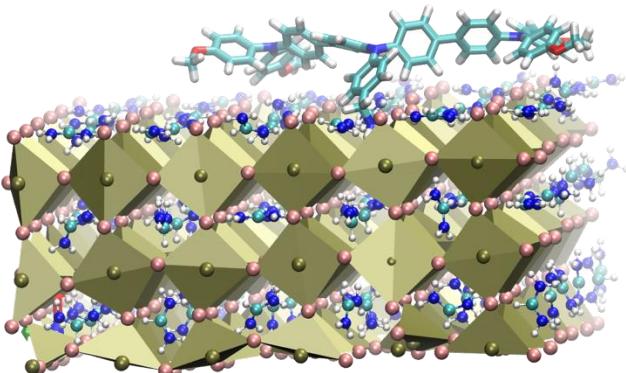
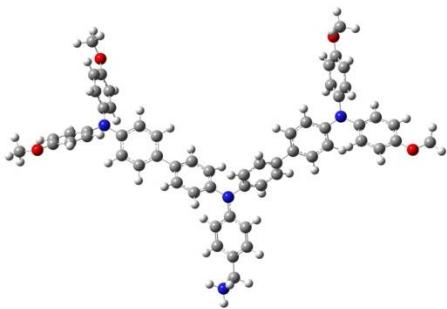
- Surface protection from moisture and defect passivation
- No active role in charge transport

BDAA



- Surface protection from moisture and defect passivation
- Good alignment with conduction and valence band → active charge transport of both electrons and holes

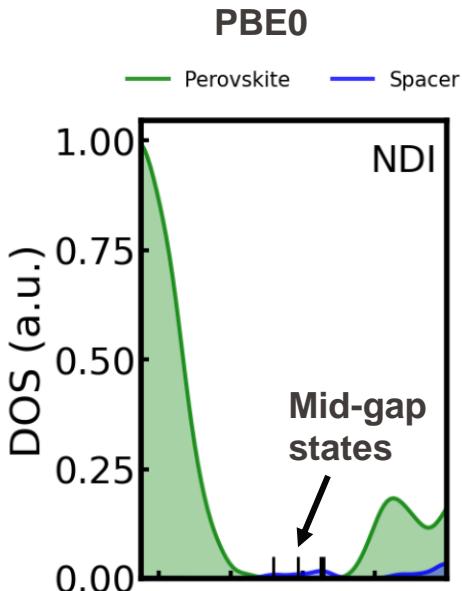
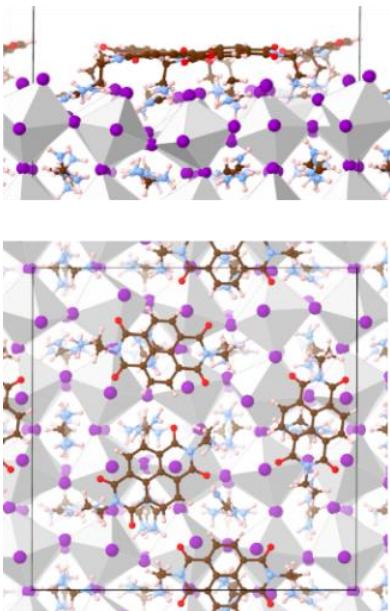
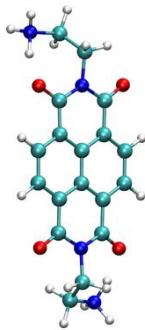
## Hole shuttle molecule (HSM)



- Good for hole selective transport (transporting holes and blocking the electrons)

# PDOS of the passivated and multilayer systems

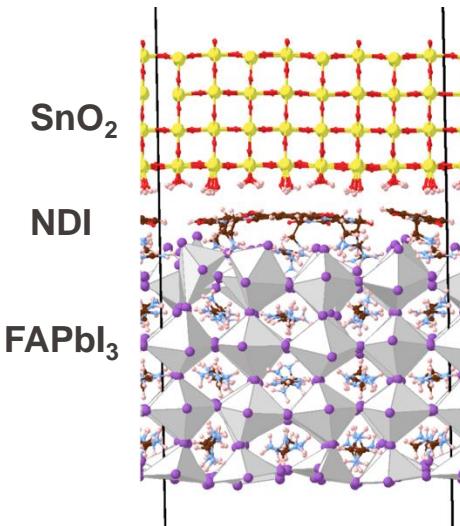
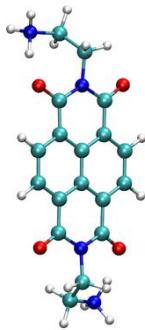
## Naphthalene diimide (NDI)



- Additives can introduce localized trap-states within the gap (not good for electron transport)

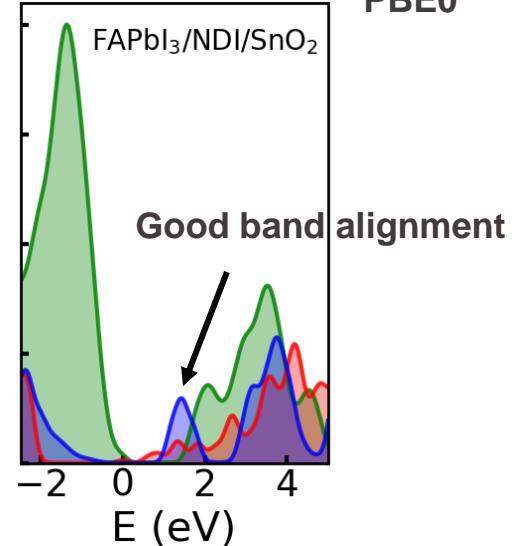
# PDOS of the passivated and multilayer systems

## Naphthalene diimide (NDI)



Perovskite       $\text{SnO}_2$       Spacer

PBE0



- However, in the actual device the energy levels of the molecules shift and have good selective carrier transport properties.

BMAA, BDAA, HSM inputs: [8Lect\\_shared](#)

Compute the PDOS alignment restarting the calculation from the wavefunctions included in the folders (the calculations will converge after a few steps)

```
&SCF
  EPS_SCF 5.0E-6
  SCF[GUESS RESTART
  ...
  ]
```



Be sure to have it in the &SCF section to have the calculation restart from the wavefunctions.

!!!Do not change the prefix in the input, otherwise cp2k will not recognize the wavefunctions!!!